

Pulse Height Analysis of 3D pCVD Diamond Detectors

RD42 Meeting

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10th May 2019

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- 3 Setup at PSI
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- 5 Analysis
- 6 Results
- 7 Conclusion
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Section 1

Introduction

Diamond as Detector Material

- innermost tracking layers \rightarrow highest radiation damage \mathcal{O} (GHz/cm²)
- \rightarrow **R&D towards more radiation tolerant detector designs and/or materials**

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Work at ETH:

- investigate signals and radiation tolerance in various detector designs:
 - ▶ Pad Detectors → whole diamond as single cell readout
 - ▶ Pixel Detectors → diamond sensor on pixel readout chip
 - ▶ 3D Pixel Detectors → 3D diamond detector on pixel readout chip

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- investigate signals and radiation tolerance in various detector designs:
 - ▶ Pad Detectors
 - ▶ Pixel Detectors
 - ▶ **3D Pixel Detectors** → this talk

Detectors

	II6-A2	II6-B6
manufacturer	II-VI Inc.	II-VI Inc.
diamond type	poly-crystal	poly-crystal
size	$\sim 4 \text{ mm} \times 4 \text{ mm}$	$\sim 4 \text{ mm} \times 4 \text{ mm}$
thickness	$\sim 500 \mu\text{m}$	$455 \mu\text{m}$
irradiation	none	none
construction	summer 2016	summer 2017
3D drilling	Oxford	Oxford
3D cell size	$150 \mu\text{m} \times 100 \mu\text{m}$	$50 \mu\text{m} \times 50 \mu\text{m}$
columns	20×30 (600)	60×62 (3720)
pixel chip	PSI46digV2.1respin (CMS)	PSI46digV2.1respin (CMS)
pixel pitch	$150 \mu\text{m} \times 100 \mu\text{m}$	$150 \mu\text{m} \times 100 \mu\text{m}$
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Table: 3D Pixel Detector Properties.

- II6-A2 broke in October 2016 (chip malfunctioned) → successful re-bonding
- II6-B6 has long history of breaking ...

Measurements

	Oct 16	May 17	Aug 17	Sep 18	Oct 18	Oct 18
place	PSI	PSI	PSI	CERN	CERN	PSI
I16-A2	✓	✓	✓	✓	✓	✓
I16-B6	✗	✗	✓	✗	✓	✓

Table: 3D Pixel Detector Measurements.

- at PSI: scanning particle rate, bias voltage, rise time and incident angle
- at CERN: high resolution studies at different voltages

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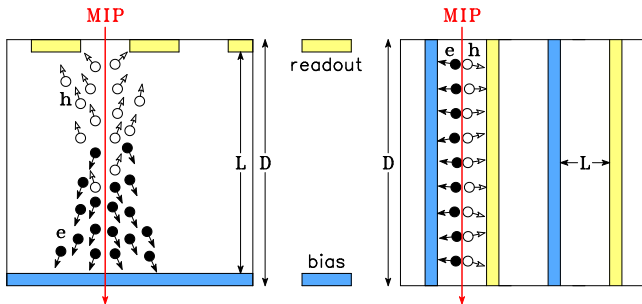
History of II6-B2:

- 06/2017 - sensor processing and detector fabrication
- 08/2017 - first measurement → high efficiency → pedestal in pulse height
- 04/2018 - several pixels malfunction → re-bump-bonding to new chip
- 06/2018 - sensor detaches while shipping → re-bump-bonding, fixate with silguard
- 10/2018 - at PSI: efficiency worsens and sensor detaches again

Section 2

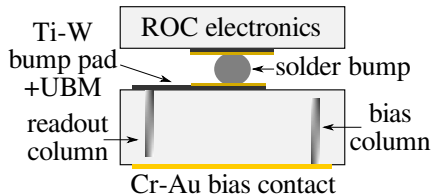
3D Pixel Detector

Working Principle

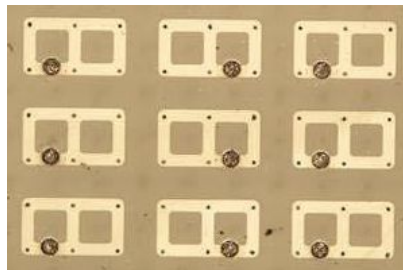


- after large radiation fluence all detectors become trap limited
- bias and readout electrode inside detector material
- same thickness $D \rightarrow$ same amount of induced charge \rightarrow shorter drift distance L
- **increase collected charge in detectors with limited mean drift path (Schubweg)**

Bump Bonding



(a) Bump bond schematics



(b) 3×2 bump pads

- electrodes (columns) drilled with femto-second laser
- connection to bias and readout with surface metallisation
- ganging of cells to match pixel pitch of readout-chip (ROC)
- small gap ($\sim 15 \mu\text{m}$) to the surface to avoid a high voltage break-through

Section 3

Setup at PSI

Pixel Telescope

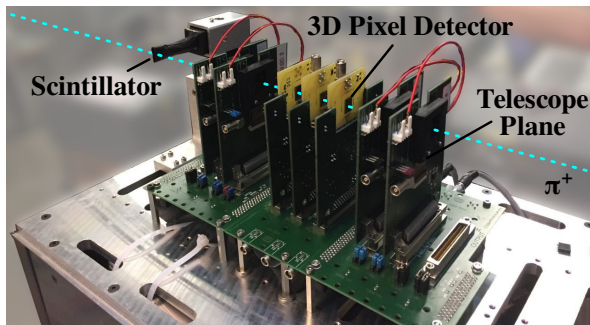
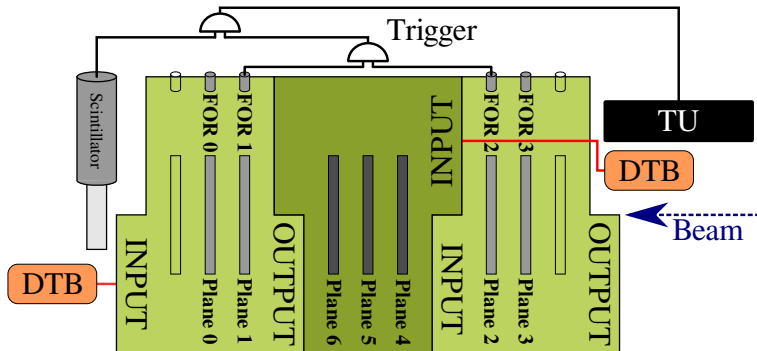


Figure: modular ETH beam telescope in pixel configuration

- 4 tracking planes \rightarrow trigger (fast-OR) \rightarrow adjustable area (max 8 mm \times 7.8 mm)
- up to 3 DUT planes (any digital pixel detector)
- scintillator for precise trigger timing $\rightarrow \mathcal{O}(1\text{ ns})$

Schematic Setup

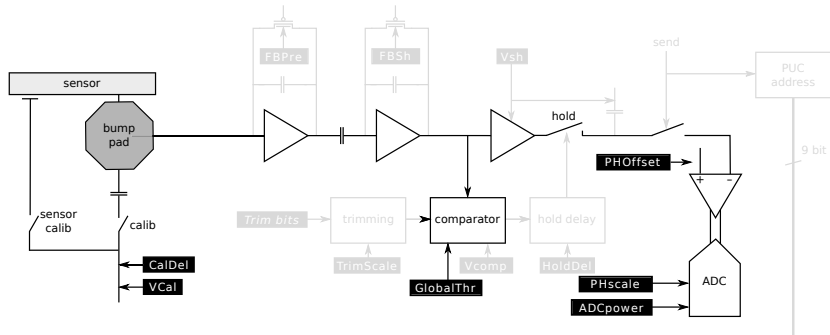


- independent telescope module for DUTs (dark green)
- scintillator → precise trigger timing of $\mathcal{O}(1 \text{ ns})$
- Trigger Unit (TU) → strongly simplifying setup
- global trigger → (Plane 1 AND Plane 2) AND Scintillator

Section 4

Pulse Height Calibration

Pixel Unit Cell



- inject calibration signal ($\sim v_{cal}$) through sensor into same circuit as real signals
- shaping, amplification, threshold check
- set amplification offset
- convert to 8 bit adc value with adjustable scale \rightarrow readout

ADC Calibration

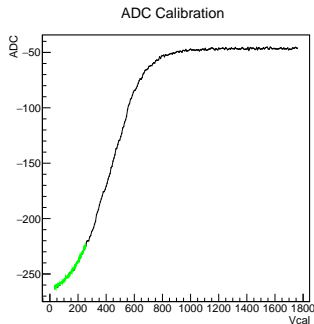


Figure: ADC calibration for single pixel.

- measure adc values for calibration pulses with different vcal
- adc follows error function and saturates for high vcal

ADC Calibration

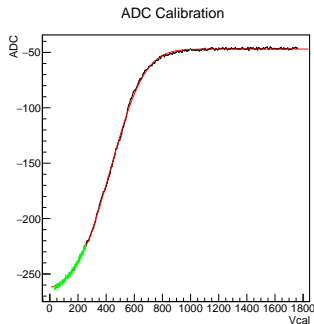
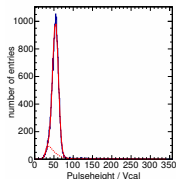


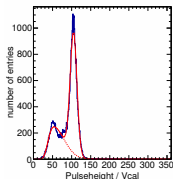
Figure: ADC calibration for single pixel with error function fit.

- measure adc values for calibration pulses with different vcal
- adc follows error function and saturates for high vcal
- fit every pixel and save fit parameters
- adjust adc offset and range with DACs of the chip

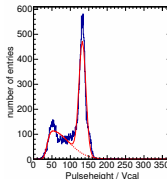
Vcal Calibration (Silicon)



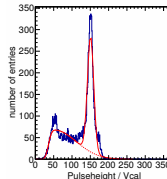
(a) Zn target.



(b) Mo target.



(a) Ag target.



(b) Sn target.

- measure energy spectra of K_{α} lines of four metal targets using ADC-calibration

Vcal Calibration (Silicon)

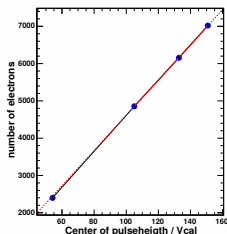
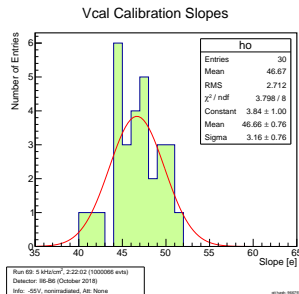


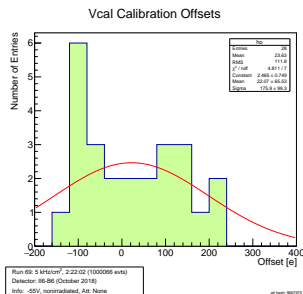
Figure: Vcal Calibration.

- measure energy spectra of K_{α} lines of four metal targets using ADC-calibration
- linear dependence of energy [e] and vcal
- fit K_{α} points with straight line (similar for each chip)
- impossible to do calibration with diamond (energy too low)

Vcal Calibration (Silicon)



(a) Vcal slopes.



(b) Vcal offsets.

- measure energy spectra of K_α lines of four metal targets using ADC-calibration
- linear dependence of energy [e] and vcal
- fit K_α points with straight line (similar for each chip)
- impossible to do calibration with diamond (energy too low)
 - use general values from silicon: $e = 46.5 \cdot \text{vcal}$

Section 5

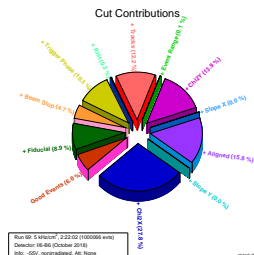
Analysis

Cuts

Cut	Excluded Events
event range	first minute of the run due to various beam conditions
beam interruptions	during rate changes of the beam due to beam interruption
aligned	DUT and Telescope are not aligned (event-wise)
trigger phase	Chip trigger timing is incorrect
tracks	not all telescope planes have exactly one cluster
chi2 (x/y)	badly fit tracks ($>50\%$ quantile)
track slope (x/y)	large angles of the tracks (>2 deg)
rhit	large DUT residual (>100 mm)
pixel mask	noisy pixels
fiducial	not in selected (fiducial) area of the DUT

Table: Analysis cut flow.

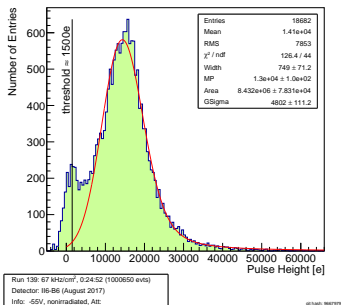
- cuts applied in order of the table
- largest contribution usually by chi2, tracks and fiducial cuts



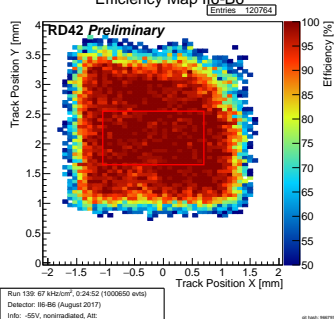
Section 6

Results

Pulse Height Distribution - II6-B6

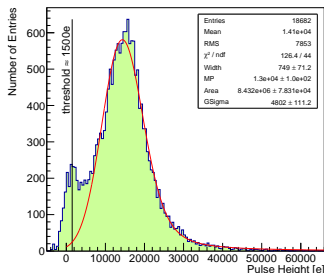


Efficiency Map II6-B6



- pulse height looks OK, but “pedestal” of unknown origin (cannot be real)
 - ▶ cannot be remeasured, since the ROC was exchanged
- Langau MPV: 13 500 e
- uniform efficiency

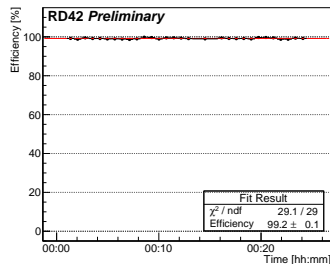
Pulse Height Distribution - I16-B6



Run 139: 67 kHz/cm², 0:24:52 (1000650 evts)
 Detector: I16-B6 (August 2017)
 Info: -55V, nonirradiated, Att:

g4-had: 00007979

Hit Efficiency I16-B6

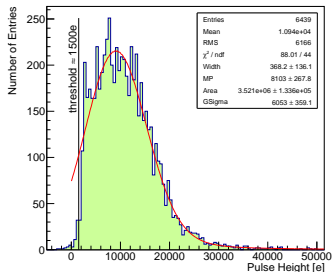


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- pulse height looks OK, but “pedestal” of unknown origin (cannot be real)
 - cannot be remeasured, since the ROC was exchanged
- Langau MPV: 13 500 e
- uniform efficiency
- high efficiency of $(99.2 \pm 0.1) \%$

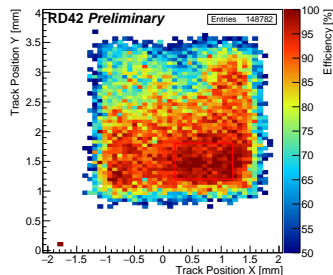
Pulse Height Distribution - II6-B6



Run 69: 5 kHz/cm², 2.22-02 (1000066 evts)
 Detector: II6-B6 (October 2018)
 Info: -55V, nonirradiated, Att: None

git hash: 9a9c979

Efficiency Map II6-B6

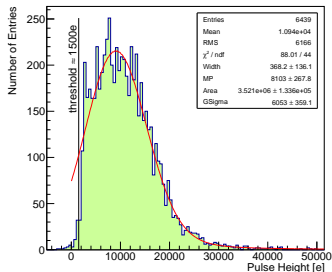


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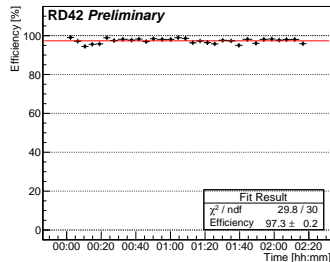
- left part of pulse height distribution not understood
- Langau MPV: 8000 e
- efficiency much less uniform \rightarrow already loose bumps?

Pulse Height Distribution - II6-B6



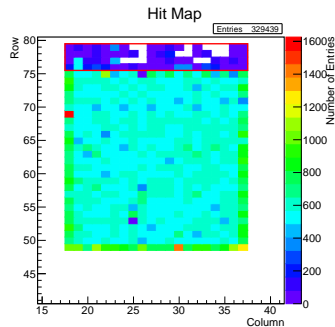
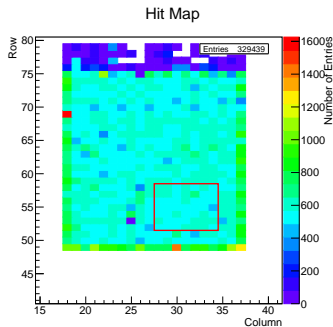
gr:bach: 10/07/19

Hit Efficiency II6-B6



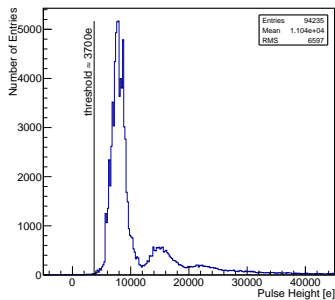
gr:bach: 10/07/19

- left part of pulse height distribution not understood
- Langau MPV: 8000 e
- efficiency much less uniform → already loose bumps?
- lower efficiency of $(97.3 \pm 0.2) \%$

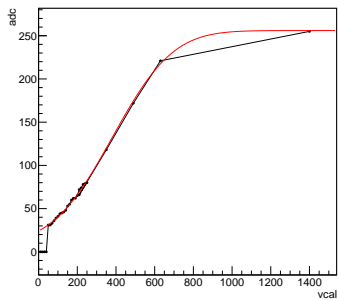


- tried different calibrations of the chip
- using the same region as at PSI
- also small region with 3D cells without bump-bonding (rows 76-79)

Pulse Height Distribution

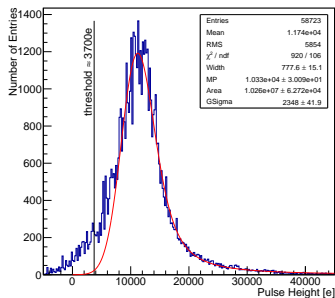


Calibration Fit for Pix 31 55

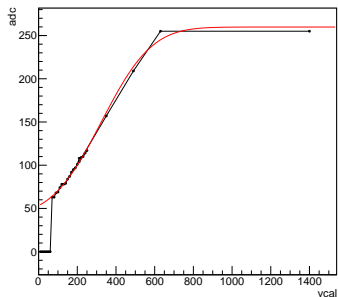


- calibration on the bench for single plane, operation with three planes
- error fit to demonstrate the calibration for a single pixel
- calibration clearly wrong

Pulse Height Distribution

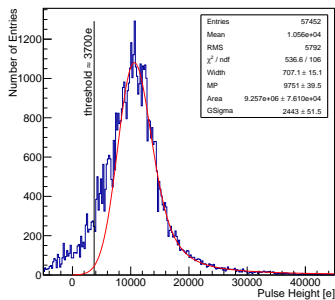


Calibration Fit for Pix 31 55

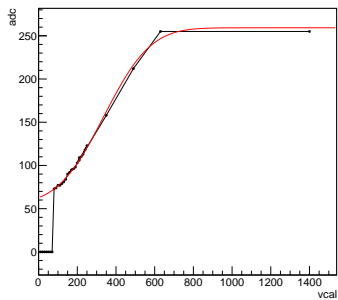


- calibration in situ, operation with three planes
- weird low side of the distribution

Pulse Height Distribution

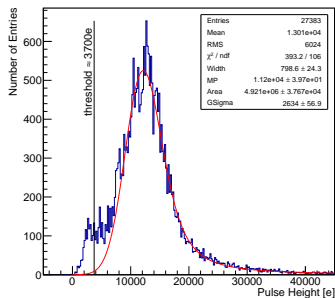


Calibration Fit for Pix 31 55

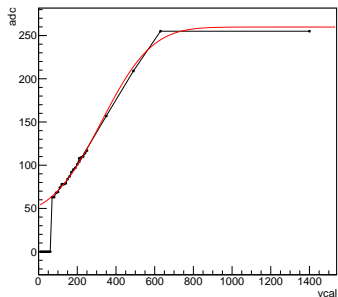


- re-calibration in situ, operation with three planes
- gives very similar result
- all calibrations in situ very similar.

Pulse Height Distribution

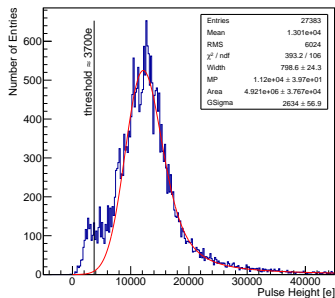


Calibration Fit for Pix 31 55



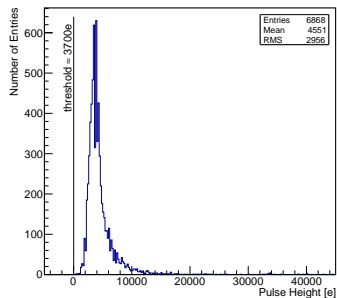
- calibration in situ, operation with single plane
- distribution looks very well, but still small negative contribution
- \rightarrow small/negative signals can be related to small/degraded analogue signals...

Pulse Height Distribution



(a) Area with 3D columns.

Pulse Height Distribution



(b) Area without 3D columns.

- comparison between regions with and without 3D columns

Section 7

Conclusion

Conclusion

- many different measurement of both 3D diamond detectors
 - ▶ start analyse more data!
- X-ray pulse height calibration can hardly be performed on diamond
 - ▶ need to use estimate from silicon
- in situ adc calibration is quite constant
- almost all pulse height distribution show nonphysical low contribution
 - ▶ possible reason: degraded analogue signals from chip to readout

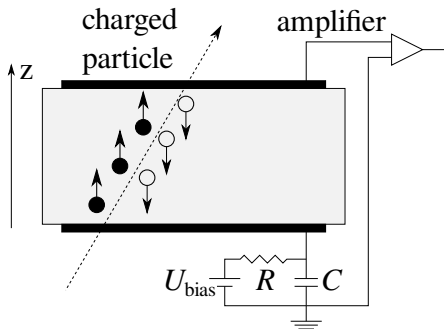
DEL FIN



Section 8

Backup

Diamond as Particle Detector



(a) Detector Schematics



(b) 15 cm \varnothing pCVD Diamond Wafer

- detectors operated as ionisation chambers
- metallisation on both sides
- poly-crystals produced in large wafers